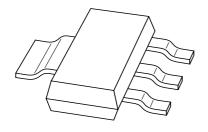
## **DISCRETE SEMICONDUCTORS**

## DATA SHEET



# **BCP69**PNP medium power transistor

Product specification Supersedes data of 1999 Apr 08 2002 Nov 15





## **PNP** medium power transistor

**BCP69** 

#### **FEATURES**

- High current (max. 1 A)
- Low voltage (max. 20 V).

#### **APPLICATIONS**

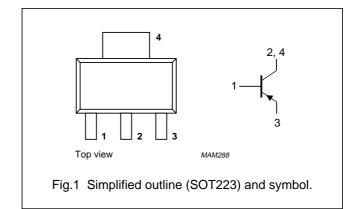
- · General purpose switching and amplification
- Power applications such as audio output stages.

#### **DESCRIPTION**

PNP medium power transistor in a SOT223 plastic package. NPN complement: BCP68.

#### **PINNING**

PIN	DESCRIPTION
1	base
2, 4	collector
3	emitter



#### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>CBO</sub>	collector-base voltage	open emitter	_	-32	V
V <sub>CEO</sub>	collector-emitter voltage	open base	_	-20	V
V <sub>EBO</sub>	emitter-base voltage	open collector	_	<b>-</b> 5	V
I <sub>C</sub>	collector current (DC)		_	<b>-1</b>	Α
I <sub>CM</sub>	peak collector current		_	-2	А
I <sub>BM</sub>	peak base current		_	-200	mA
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	1.35	W
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C

#### Note

1. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm<sup>2</sup>. For other mounting conditions, see *"Thermal considerations for SOT223 in the General Part of associated Handbook"*.

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#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	91	K/W
R <sub>th j-s</sub>	thermal resistance from junction to soldering point		10	K/W

#### Note

1. Device mounted on a printed-circuit board, single-sided copper, tinplated, mounting pad for collector 1 cm<sup>2</sup>. For other mounting conditions, see *"Thermal considerations for SOT223 in the General Part of associated Handbook"*.

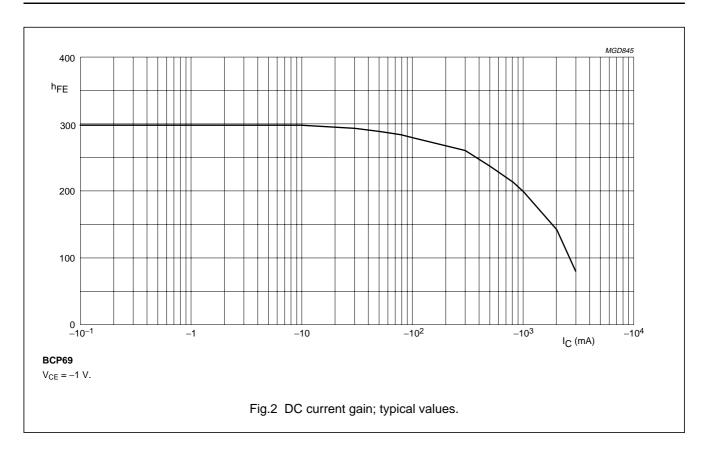
#### **CHARACTERISTICS**

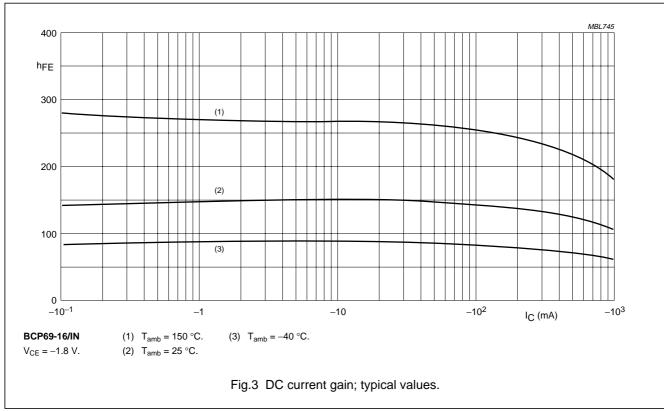
 $T_j = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I <sub>CBO</sub>	collector cut-off current	$I_E = 0; V_{CB} = -25 \text{ V}$	_	_	-100	nA
		I <sub>E</sub> = 0; V <sub>CB</sub> = -25 V; T <sub>j</sub> = 150 °C	_	_	-10	μΑ
I <sub>EBO</sub>	emitter cut-off current	$I_C = 0; V_{EB} = -5 \text{ V}$	_	_	-100	nA
h <sub>FE</sub>	DC current gain	$I_C = -5 \text{ mA}; V_{CE} = -10 \text{ V}$	50	_	_	
		$I_C = -500 \text{ mA}; V_{CE} = -1 \text{ V}; \text{ see Fig.2}$	85	_	375	
		$I_C = -1 \text{ A}; V_{CE} = -1 \text{ V}; \text{ see Fig.2}$	60	_	_	
	DC current gain	$I_C = -500 \text{ mA}; V_{CE} = -1 \text{ V}; \text{ see Fig.2}$				
	BCP69-16		100	_	250	
	BCP69-25		160	_	375	
	DC current gain	$I_C = -10 \text{ mA}; V_{CE} = -1.8 \text{ V}; \text{ see Fig.3}$				
	BCP69-16/IN		140	_	230	
V <sub>CEsat</sub>	collector-emitter saturation voltage	$I_C = -1 \text{ A}; I_B = -100 \text{ mA}$	_	_	-500	mV
V <sub>BE</sub>	base-emitter voltage	$I_C = -5 \text{ mA}; V_{CE} = -10 \text{ V}$	_	-620	_	mV
		$I_C = -1 A; V_{CE} = -1 V$	_	_	-1	٧
C <sub>c</sub>	collector capacitance	$I_E = i_e = 0$ ; $V_{CB} = -5 \text{ V}$ ; $f = 1 \text{ MHz}$	_	48	_	pF
f <sub>T</sub>	transition frequency	$I_C = -10 \text{ mA}; V_{CE} = -5 \text{ V}; f = 100 \text{ MHz}$	40	_	_	MHz
h <sub>FE1</sub> h <sub>FE2</sub>	DC current gain ratio of the complementary pairs	$ I_C  = 0.5 \text{ A};  V_{CE}  = 1 \text{ V}$	_	_	1.6	

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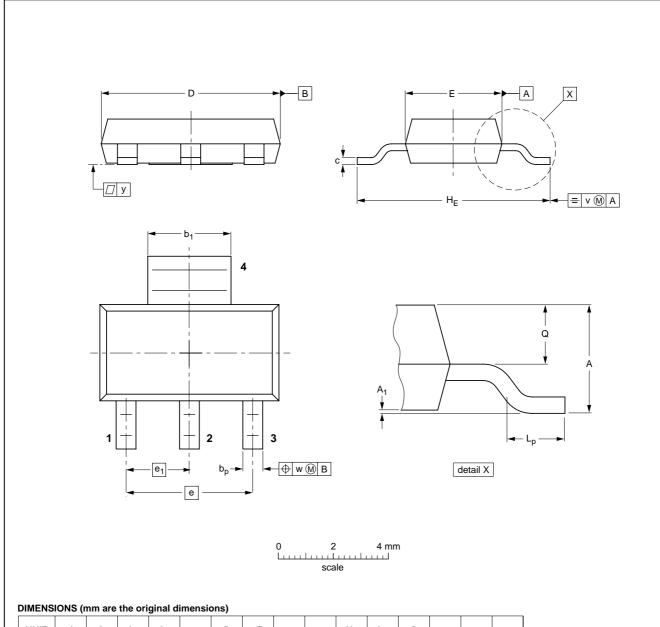
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#### **PACKAGE OUTLINE**

Plastic surface mounted package; collector pad for good heat transfer; 4 leads

**SOT223** 



UNI	А	A <sub>1</sub>	bp	b <sub>1</sub>	С	D	E	е	e <sub>1</sub>	HE	Lp	Q	٧	w	у
mm	1.8 1.5	0.10 0.01	0.80 0.60	3.1 2.9	0.32 0.22	6.7 6.3	3.7 3.3	4.6	2.3	7.3 6.7	1.1 0.7	0.95 0.85	0.2	0.1	0.1

OUTLINE		REFER	EUROPEAN	ICCUE DATE		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT223			SC-73			<del>97-02-28</del> 99-09-13

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#### **DATA SHEET STATUS**

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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